



Integrated
Circuit
Systems, Inc.

ICS8701

Low Skew $\div 1, \div 2$
CLOCK GENERATOR

GENERAL DESCRIPTION

The ICS8701 is a low skew, $\div 1, \div 2$ Clock Generator and a member of the HiPerClockS™ family of High Performance Clock Solutions from ICS. The low impedance LVCMOS outputs are designed to drive 50Ω series or parallel terminated transmission lines. The effective fanout can be increased from 20 to 40 by utilizing the ability of the outputs to drive two series terminated lines.

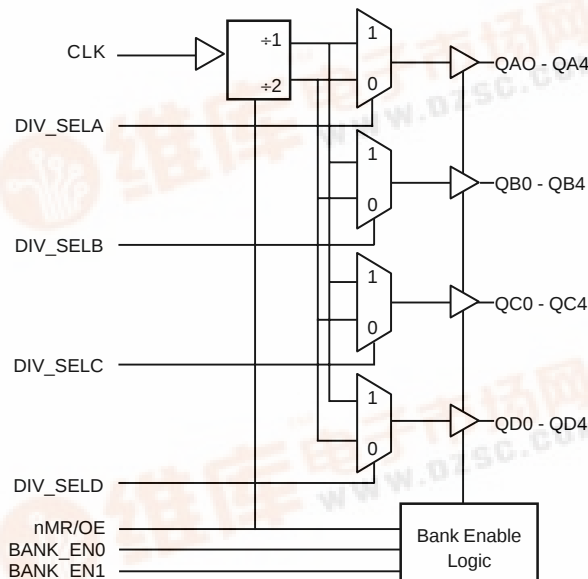
The divide select inputs, DIV_SELx, control the output frequency of each bank. The outputs can be utilized in the $\div 1, \div 2$ or a combination of $\div 1$ and $\div 2$ modes. The bank enable inputs, BANK_EN0:1, support enabling and disabling each bank of outputs individually. The master reset input, nMR/OE, resets the internal frequency dividers and also controls the active and high impedance states of all outputs.

The ICS8701 is characterized at 3.3V and mixed 3.3V input supply, and 2.5V output supply operating modes. Guaranteed bank, output and part-to-part skew characteristics make the ICS8701 ideal for those clock distribution applications demanding well defined performance and repeatability.

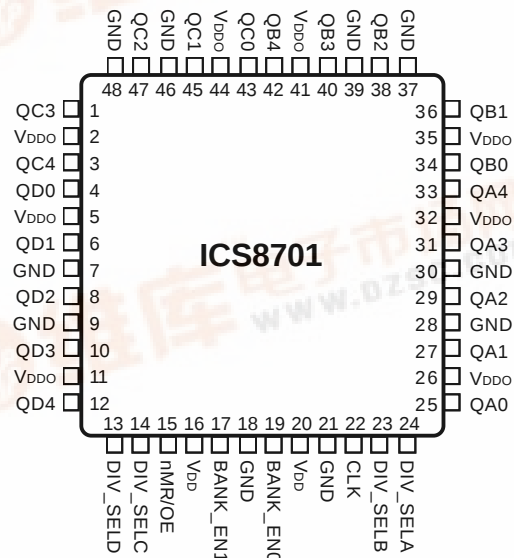
FEATURES

- 20 LVCMOS outputs, 7Ω typical output impedance
- 1 LVCMOS clock input
- Maximum output frequency up to 250MHz
- Bank enable logic allows unused banks to be disabled in reduced fanout applications
- Output skew: 250ps (maximum)
- Part-to-part skew: 600ps (maximum)
- Bank skew: 200ps (maximum)
- Multiple frequency skew: 300ps (maximum)
- 3.3V or mixed 3.3V input, 2.5V output operating supply modes
- 0°C to 70°C ambient operating temperature
- Other divide values available on request

BLOCK DIAGRAM



PIN ASSIGNMENT



48-Pin LQFP

7mm x 7mm x 1.4mm

Y Package

Top View





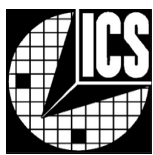
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TABLE 1. PIN DESCRIPTIONS

Number	Name	Type		Description
2, 5, 11, 26, 32, 35, 41, 44	V _{DDO}	Power		Output supply pins. Connect to 3.3V or 2.5V.
7, 9, 18, 21, 28, 30, 37, 39, 46, 48	GND	Power		Power supply ground. Connect to ground.
16, 20	V _{DD}	Power		Positive supply pins. Connect to 3.3V.
25, 27, 29, 31, 33	QA0, QA1, QA2, QA3, QA4	Output		Bank A outputs. LVCMOS interface levels. 7 Ω typical output impedance.
34, 36, 38, 40, 42	QB0, QB1, QB2, QB3, QB4	Output		Bank B outputs. LVCMOS interface levels. 7 Ω typical output impedance.
43, 45, 47, 1, 3	QC0, QC1, QC2, QC3, QC4	Output		Bank C outputs. LVCMOS interface levels. 7 Ω typical output impedance.
4, 6, 8, 10, 12	QD0, QD1, QD2, QD3, QD4	Output		Bank D outputs. LVCMOS interface levels 7 Ω typical output impedance.
22	CLK	Input	Pulldown	LVCMOS / LVTTL clock input.
13	DIV_SELD	Input	Pullup	Controls frequency division for bank D outputs. LVCMOS interface levels.
14	DIV_SEL C	Input	Pullup	Controls frequency division for bank C outputs. LVCMOS interface levels.
23	DIV_SEL B	Input	Pullup	Controls frequency division for bank B outputs. LVCMOS interface levels.
24	DIV_SEL A	Input	Pullup	Controls frequency division for bank A outputs. LVCMOS interface levels.
17, 19	BANK_EN1, BANK_EN0	Input	Pullup	Enables and disables outputs by banks. LVCMOS interface levels.
15	nMR/OE	Input	Pullup	Master reset and output enable. Enables and disables all outputs. LVCMOS interface levels.



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TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance	CLK				4	pF
		DIV_SELA, DIV_SELB, DIV_SELc, DIV_SELD, BANK_EN0, NMR/OE, BANK_EN1,				4	
R_{PULLUP}	Input Pullup Resistor				51		K Ω
$R_{PULLDOWN}$	Input Pulldown Resistor				51		K Ω
C_{PD}	Power Dissipation Capacitance (per output)		$V_{DD}, V_{DDO} = 3.465V$				pF
			$V_{DD} = 3.465V,$ $V_{DDO} = 2.625V$				pF
R_{OUT}	Output Impedance				7		Ω

TABLE 3. FUNCTION TABLE

Inputs				Outputs				
nMR/OE	BANK_EN1	BANK_EN0	DIV_SELx	QA0 - QA4	QB0 - QB4	QC0 - QC4	QD0 - QD4	Qx frequency
0	X	X	X	Hi Z	Hi Z	Hi Z	Hi Z	zero
1	0	0	0	Active	Hi Z	Hi Z	Hi Z	fIN/2
1	1	0	0	Active	Active	Hi Z	Hi Z	fIN/2
1	0	1	0	Active	Active	Active	Hi Z	fIN/2
1	1	1	0	Active	Active	Active	Active	fIN/2
1	0	0	1	Active	Hi Z	Hi Z	Hi Z	fIN
1	1	0	1	Active	Active	Hi Z	Hi Z	fIN
1	0	1	1	Active	Active	Active	Hi Z	fIN
1	1	1	1	Active	Active	Active	Active	fIN



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ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DDx}	4.6V
Inputs, V_I	-0.5V to $V_{DD} + 0.5V$
Outputs, V_O	-0.5V to $V_{DDO} + 0.5V$
Package Thermal Impedance, θ_{JA}	47.9°C/W (0lfpm)
Storage Temperature, T_{STG}	-65°C to 150°C

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress **specifications only**. **Functional operation of product at these conditions** or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 4A. POWER SUPPLY DC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Quiescent Power Supply Current	$V_{DD} = V_{IH} = 3.465V$ $V_{IL} = 0V$			95	mA

TABLE 4B. LVCMOS DC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	DIV_SELA, DIV_SELB, DIV_SELc, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	2		3.8	V
		CLK	2		3.8	V
V_{IL}	Input Low Voltage	DIV_SELA, DIV_SELB, DIV_SELc, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	$V_{DD} = 3.465V$	-0.3	0.8	V
		CLK	$V_{DD} = 3.465V$	-0.3	1.3	V
I_{IH}	Input High Current	DIV_SELA, DIV_SELB, DIV_SELc, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	$V_{DD} = V_{IN} = 3.465V$		5	μA
		CLK	$V_{DD} = V_{IN} = 3.465V$		150	μA
I_{IL}	Input Low Current	DIV_SELA, DIV_SELB, DIV_SELc, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	$V_{DD} = 3.465V, V_{IN} = 0V$	-150		μA
		CLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5		μA
V_{OH}	Output High Voltage	$V_{DD} = V_{DDO} = 3.135V$ $I_{OH} = -36mA$	2.6			V
V_{OL}	Output Low Voltage	$V_{DD} = V_{DDO} = 3.135V$ $I_{OL} = 36mA$			0.5	V



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TABLE 5A. AC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Maximum Input Frequency				250	MHz
t_{PD}	Propagation Delay; NOTE 1	$0MHz \leq f \leq 200MHz$	2.2		3.4	ns
$tsk(b)$	Bank Skew; NOTE 2, 7	Measured on rising edge at $V_{DDO}/2$			200	ps
$tsk(o)$	Output Skew; NOTE 3, 7	Measured on rising edge at $V_{DDO}/2$			250	ps
$tsk(w)$	Multiple Frequency Skew; NOTE 4, 7	Measured on rising edge at $V_{DDO}/2$			300	ps
$tsk(pp)$	Part-to-Part Skew; NOTE 5, 7	Measured on rising edge at $V_{DDO}/2$			600	ps
t_R	Output Rise Time; NOTE 6	30% to 70%	280		850	ps
t_F	Output Fall Time; NOTE 6	30% to 70%	280		850	ps
odc	Output Duty Cycle	$0MHz \leq f \leq 200MHz$	$t_{CYCLE}/2 - 0.5$	$t_{CYCLE}/2$	$t_{CYCLE}/2 + 0.5$	ns
		$f = 200MHz$	2	2.5	3	ns
t_{EN}	Output Enable Time; NOTE 6	$f = 10MHz$			6	ns
t_{DIS}	Output Disable Time; NOTE 6	$f = 10MHz$			6	ns

All parameters measured at 200MHz unless noted otherwise.

NOTE 1: Measured from the 50% point of the input to the output crossing point.

NOTE 2: Defined as skew within a bank of outputs at the same supply voltages and with equal load conditions.

NOTE 3: Defined as skew across banks of outputs at the same supply voltages and with equal load conditions.

NOTE 4: Defined as skew across banks of outputs operating at different frequency with the same supply voltages and equal load conditions.

NOTE 5: Defined as the skew at between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the cross points.

NOTE 6: These parameters are guaranteed by characterization. Not tested in production.

NOTE 7: This parameter is defined in accordance with JEDEC Standard 65.



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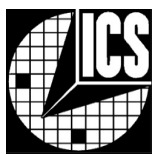
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TABLE 4C. POWER SUPPLY DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Quiescent Power Supply Current	$V_{DD} = V_{IH} = 3.465V$ $V_{IL} = 0V$			95	mA

TABLE 4D. LVCMOS DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	DIV_SELA, DIV_SELB, DIV_SEL, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	2		3.8	V
		CLK	2		3.8	V
V_{IL}	Input Low Voltage	$V_{DD} = 3.465V$ DIV_SELA, DIV_SELB, DIV_SEL, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	-0.3		0.8	V
		$V_{DD} = 3.465V$ CLK	-0.3		1.3	V
I_{IH}	Input High Current	$V_{DD} = V_{IN} = 3.465V$ DIV_SELA, DIV_SELB, DIV_SEL, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE			5	μA
		$V_{DD} = V_{IN} = 3.465V$ CLK			150	μA
I_{IL}	Input Low Current	$V_{DD} = 3.465V, V_{IN} = 0V$ DIV_SELA, DIV_SELB, DIV_SEL, DIV_SELD, BANK_EN0, BANK_EN1, nMR/OE	-150			μA
		$V_{DD} = 3.465V, V_{IN} = 0V$ CLK	-5			μA
V_{OH}	Output High Voltage	$V_{DD} = 3.135V$, $V_{DDO} = 2.375V$ $I_{OH} = -27mA$	1.8			V
V_{OL}	Output Low Voltage	$V_{DD} = 3.135V$, $V_{DDO} = 2.375V$ $I_{OL} = 27mA$			0.5	V



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TABLE 5B. AC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Maximum Input Frequency				250	MHz
t_{PD}	Propagation Delay; NOTE 1	$0MHz \leq f \leq 200MHz$	2.6		3.6	ns
$tsk(b)$	Bank Skew; NOTE 2, 7	Measured on rising edge at $V_{DDO}/2$			225	ps
$tsk(o)$	Output Skew; NOTE 3, 7	Measured on rising edge at $V_{DDO}/2$			250	ps
$tsk(w)$	Multiple Frequency Skew; NOTE 4, 7	Measured on rising edge at $V_{DDO}/2$			300	ps
$tsk(pp)$	Part-to-Part Skew; NOTE 5, 7	Measured on rising edge at $V_{DDO}/2$			600	ps
t_R	Output Rise Time; NOTE 6	30% to 70%	280		850	ps
t_F	Output Fall Time; NOTE 6	30% to 70%	280		850	ps
odc	Output Duty Cycle	$0MHz \leq f \leq 200MHz$	$t_{CYCLE}/2 - 0.5$	$t_{CYCLE}/2$	$t_{CYCLE}/2 + 0.5$	ns
		$f = 200MHz$	2	2.5	3	ns
t_{EN}	Output Enable Time; NOTE 6	$f = 10MHz$			6	ns
t_{DIS}	Output Disable Time; NOTE 6	$f = 10MHz$			6	ns

All parameters measured at 200MHz unless noted otherwise.

NOTE 1: Measured from the 50% point of the input to the output crossing point.

NOTE 2: Defined as skew within a bank of outputs at the same supply voltages and with equal load conditions.

NOTE 3: Defined as skew across banks of outputs at the same supply voltages and with equal load conditions.

NOTE 4: Defined as skew across banks of outputs operating at different frequency with the same supply voltages and equal load conditions.

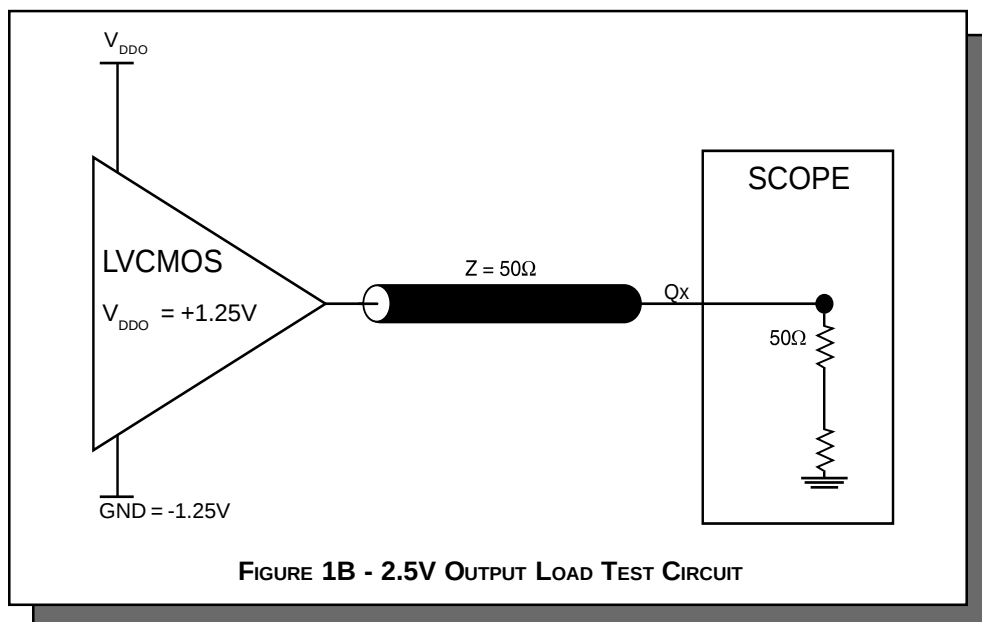
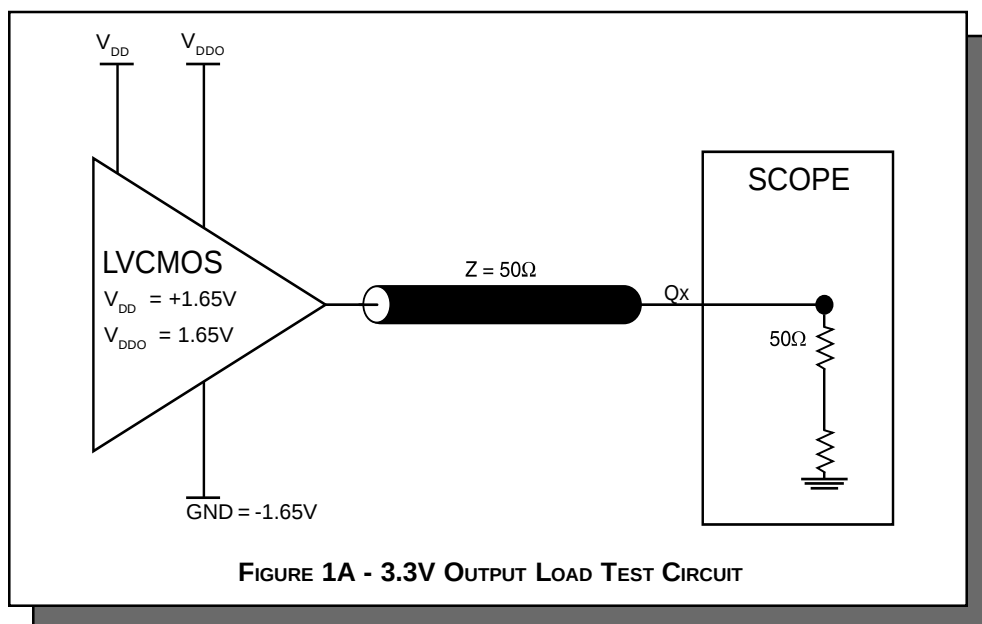
NOTE 5: Defined as the skew at between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the cross points.

NOTE 6: These parameters are guaranteed by characterization. Not tested in production.

NOTE 7: This parameter is defined in accordance with JEDEC Standard 65.



PARAMETER MEASUREMENT INFORMATION

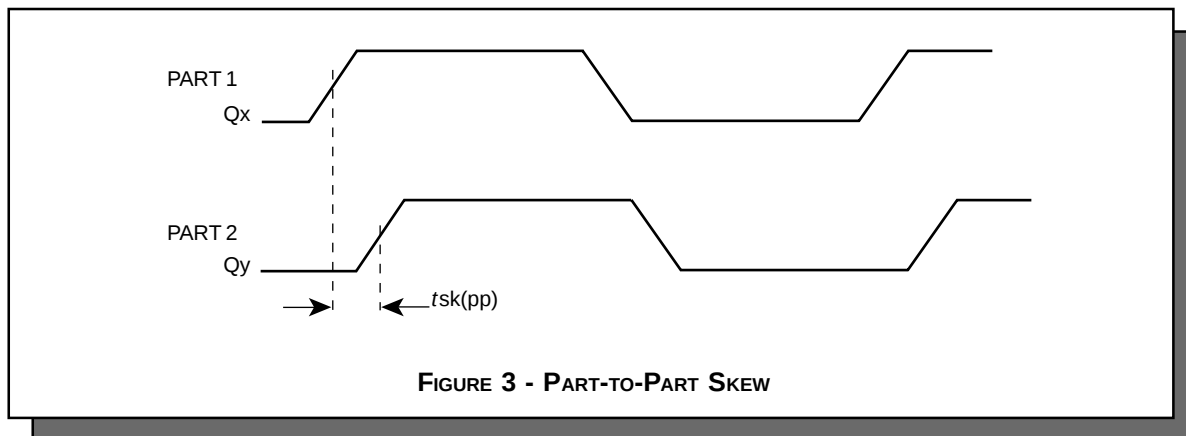
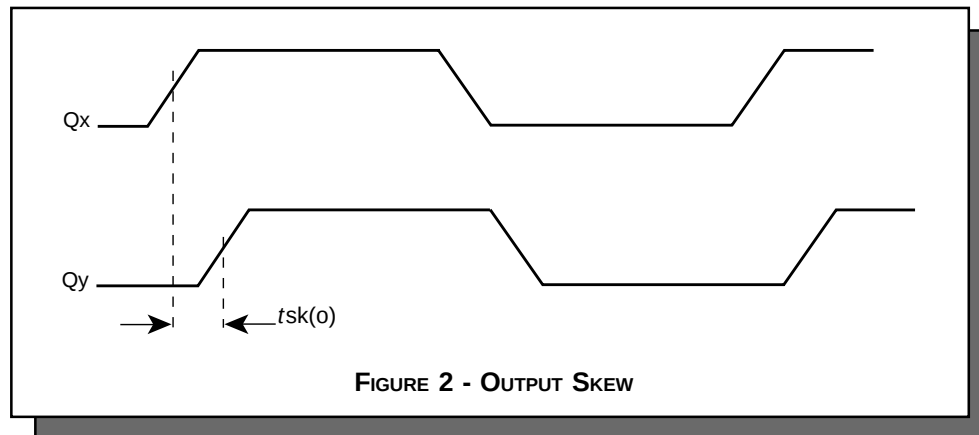


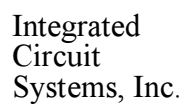


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The diagram shows a digital signal waveform labeled "Clock Inputs and Outputs". The signal transitions from a low level to a high level and back to a low level. The rise time, t_R , is the time interval between the signal reaching 20% and 80% of its full swing voltage, V_{SWING} . Similarly, the fall time, t_F , is the time interval between the signal reaching 80% and 20% of its full swing voltage. Dashed vertical lines mark the 20% and 80% voltage levels for both transitions.

FIGURE 4 - INPUT AND OUTPUT RISE AND FALL TIME

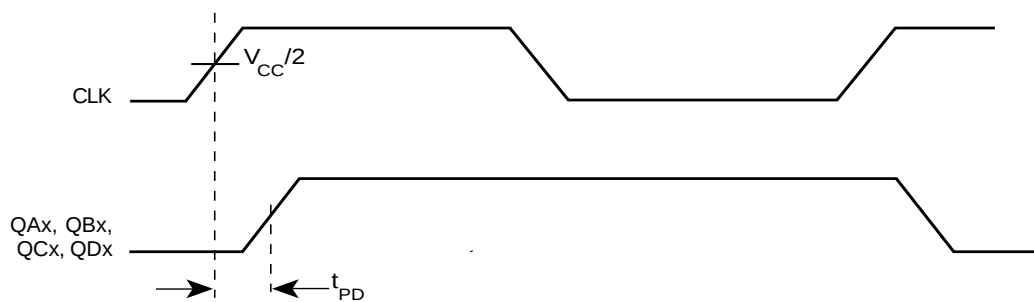


FIGURE 5 - PROPAGATION DELAY

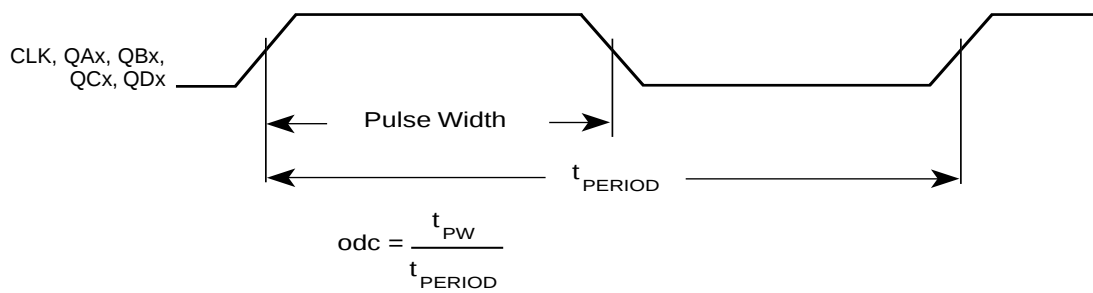
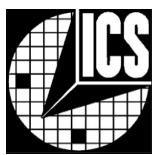


FIGURE 6 - odc & t_{PERIOD}



POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS8701-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS8701-01 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{DD_MAX} * I_{DD_MAX} = 3.465V * 95mA = 329.2mW$
- Power (outputs)_{MAX} = **32mW/Loaded Output pair**
If all outputs are loaded, the total power is $20 * 32mW = 640mW$

Total Power_{MAX} (3.465V, with all outputs switching) = $329.2mW + 640mW = 969.2mW$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS™ devices is 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = junction-to-ambient thermal resistance

Pd_total = Total device power dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 42.1°C/W per Table 6 below. Therefore, T_j for an ambient temperature of 70°C with all outputs switching is:

$70^\circ C + 0.969W * 42.1^\circ C/W = 110.8^\circ C$. This is well below the limit of 125°C

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

Table 6. Thermal Resistance θ_{JA} for 48-pin LQFP, Forced Convection

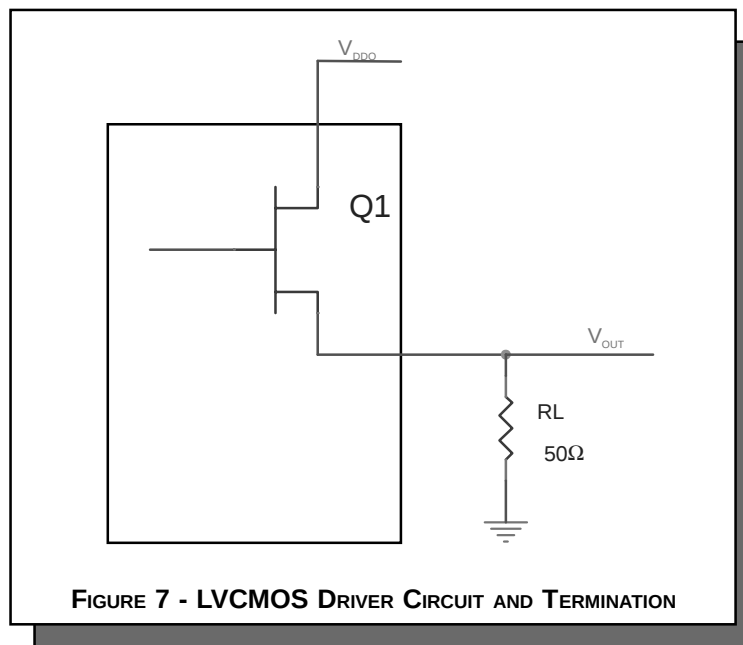
θ_{JA} by Velocity (Linear Feet per Minute)			
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W
NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.			



3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVC MOS output driver circuit and termination are shown in *Figure 7*.



To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of $V_{DD} - 2V$.

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = (V_{OH_MAX} / R_L) * (V_{DD_MAX} - V_{OH_MAX})$$

$$Pd_L = (V_{OL_MAX} / R_L) * (V_{DD_MAX} - V_{OL_MAX})$$

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{DD_MAX} - 1.2V$
- For logic low, $V_{OUT} = V_{OL_MAX} = V_{DD_MAX} - 0.4V$

$$Pd_H = (1.2V / 50\Omega) * (2V - 1.2V) = \mathbf{19.2mW}$$

$$Pd_L = (0.4V / 50\Omega) * (2V - 0.4V) = \mathbf{12.8mW}$$

$$\text{Total Power Dissipation per output pair} = Pd_H + Pd_L = \mathbf{32mW}$$



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RELIABILITY INFORMATION

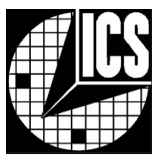
TABLE 7. θ_{JA} VS. AIR FLOW TABLE

θ_{JA} by Velocity (Linear Feet per Minute)			
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS8701 is: 1743



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PACKAGE OUTLINE - Y SUFFIX

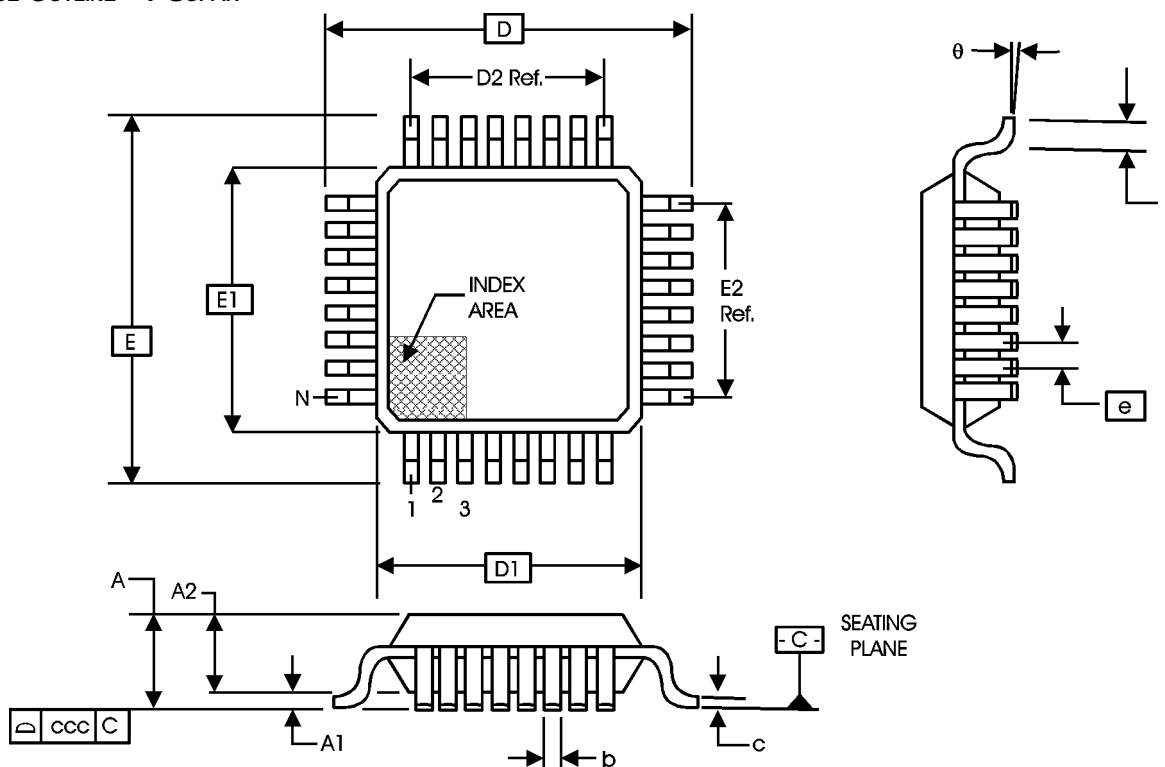


TABLE 8. PACKAGE DIMENSIONS

JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS			
SYMBOL	BBC		
	MINIMUM	NOMINAL	MAXIMUM
N	48		
A	--	--	1.60
A1	0.05	--	0.15
A2	1.35	1.40	1.45
b	0.17	0.22	0.27
c	0.09	--	0.20
D	9.00 BASIC		
D1	7.00 BASIC		
D2	5.50 Ref.		
E	9.00 BASIC		
E1	7.00 BASIC		
E2	5.50 Ref.		
e	0.50 BASIC		
L	0.45	0.60	0.75
θ	0°	--	7°
ccc	--	--	0.08

Reference Document: JEDEC Publication 95, MS-026



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TABLE 9. ORDERING INFORMATION

Part/Order Number	Marking	Package	Count	Temperature
ICS8701CY	ICS8701CY	48 Lead LQFP	250 per tray	0°C to 70°C
ICS8701CYT	ICS8701CY	48 Lead LQFP on Tape and Reel	1000	0°C to 70°C